TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZ32AFE

#### 2 Input OR Gate

#### **Features**

• High output drive: ±24 mA (typ.)

$$@V_{CC} = 3 V$$

• Super high speed operation: tpD 2.4 ns (typ.)

$$@V_{CC} = 5 \text{ V}, 50 \text{ pF}$$

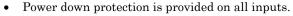
• Operation voltage range:  $V_{CC (opr)} = 1.8 \sim 5.5 \text{ V}$ 

• Supply voltage data retention:  $V_{CC} = 1.5 \sim 5.5 \text{ V}$ 

• Latch-up performance: ±500 mA

ESD performance: Human body model > ±2000 V

Machine model  $> \pm 200 \text{ V}$ 



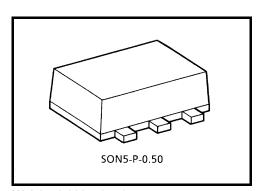
 $\bullet$  Matches the performance of TC74LCX series when operated at 3.3 V V<sub>CC</sub>

• Input rise and fall time (tr, tf) (recommended operation condition)

$$@V_{CC} = 1.8 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$$
: 0~20 ns/V

 $@V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} : 0 \sim 10 \text{ ns/V}$ 

 $@V_{CC} = 5.5 \text{ V} \pm 0.5 \text{ V}$ :  $0 \sim 5 \text{ ns/V}$ 



Weight: 0.003 g (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5~6	V
DC input voltage	V <sub>IN</sub>	-0.5~6	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	٧
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	150	mW
Storage temperature	T <sub>stg</sub>	<b>−65~150</b>	°C
Lead temperature (10 s)	TL	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# **Operating Ranges**

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Characteristics	Symbol	Rating	Unit	
Supply voltage	Voo	1.8~5.5	V	
Supply voltage	V <sub>CC</sub>	1.5~5.5 (Note 1)	v	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
		$0\sim20~(V_{CC}=1.8~V,~2.5~V\pm0.2~V)$	ns/V	
Input rise and fall time	dt/dv	$0 \sim 10 \; (V_{CC} = 3.3 \; V \pm 0.3 \; V)$		
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$		

Note 1: Data retention only.

## **Electrical Characteristics**

## **DC Characteristics**

Test					Ta = 25°C Ta = -40~85°			0~85°C					
Characteristics	Symbol	Circuit	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit		
High-level input VIH —				1.8	0.75 × V <sub>CC</sub>	_	_	0.75 × V <sub>CC</sub>	_	V			
voltage	VIΗ		_		2.3- 5.5	0.7 × V <sub>CC</sub>	_	_	0.7 × V <sub>CC</sub>		v		
Low-level input	V <sub>IL</sub>							0.25 × V <sub>CC</sub>		0.25 × V <sub>CC</sub>			
voltage	VIL			_	2.3- 5.5	_	_	0.3 × V <sub>CC</sub>	_	0.3 × V <sub>CC</sub>	V		
					1.8	1.7	1.8	_	1.7				
				I <sub>OH</sub> = -100 μA	2.3	2.2	2.3	_	2.2				
				ΙΟΗ = -100 μΑ	3.0	2.9	3.0	_	2.9		V		
High-level	VoH		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		4.5	4.4	4.5	_	4.4				
output voltage	VOH			$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9				
				I <sub>OH</sub> = -16 mA	3.0	2.4	2.8	_	2.4				
				I <sub>OH</sub> = -24 mA	3.0	2.3	2.68	_	2.3				
					I <sub>OH</sub> = -32 mA	4.5	3.8	4.2	_	3.8	_		
				I <sub>OL</sub> = 100 μA	1.8	_	0	0.1	_	0.1	-		
					2.3	_	0	0.1	_	0.1			
						10Ε = 100 μ/ (	10L = 100 μΑ	3.0	_	0	0.1	_	0.1
Low-level output	Low-level output V <sub>OL</sub> —		V <sub>IN</sub> =		4.5	—	0	0.1	_	0.1	V		
voltage		V <sub>IL</sub>	I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3	_	0.3				
			I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	_	0.4				
				I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	_	0.55			
				I <sub>OL</sub> = 32 mA	4.5	—	0.22	0.55	_	0.55			
Input leakage current	I <sub>IN</sub>	_	V <sub>IN</sub> = 5.5 V or GND		0- 5.5	_	_	±1	_	±10	μΑ		
Quiescent supply current	Icc	_	V <sub>IN</sub> = V <sub>C</sub>	<sub>C</sub> or GND	5.5	_	_	2	_	20	μА		

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#### AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
Circle Symbol Circ	Circuit	Circuit	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic	
				1.8	2.0	4.6	10.0	2.0	10.5	
Propagation delay <sup>t</sup> PLH time tPHL	_	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	$2.5\pm0.2$	0.8	3.0	7.0	0.8	7.5	- ns	
			$3.3 \pm 0.3$	0.5	2.4	4.7	0.5	5.0		
			5.0 ± 0.5	0.5	1.9	4.1	0.5	4.4		
		$\begin{array}{c} C_L = 50 \text{ pF}, \\ R_L = 500 \ \Omega \end{array}$	$3.3\pm0.3$	1.5	3.0	5.2	1.5	5.5		
			5.0 ± 0.5	0.8	2.4	4.5	8.0	4.8		
Input capacitance	C <sub>IN</sub>	_	_	0-5.5		4		_		pF
Power dissipation capacitance C <sub>F</sub>	Coo	C <sub>PD</sub> —	(Note)	3.3		19		_		- pF
	CPD			5.5	_	27	_	_	_	

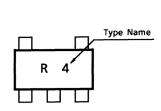
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

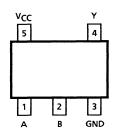
Average operating current can be obtained by the equation.

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

# Marking

# Pin Assignment (top view)



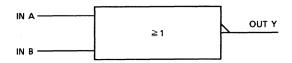


#### **Truth Table**

Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

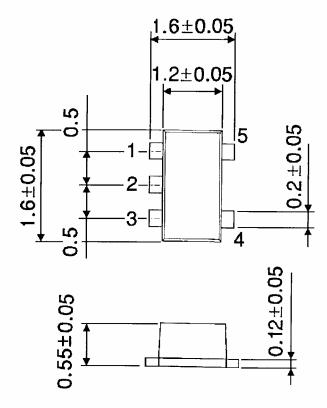
#### **Logic Diagram**

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## **Package Dimensions**

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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